

BC560C

Low Noise Transistors

PNP Silicon

Features

- These are Pb-Free Devices*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V_{CEO}	-45	Vdc
Collector - Base Voltage	V_{CBO}	-50	Vdc
Emitter - Base Voltage	V_{EBO}	-5.0	Vdc
Collector Current - Continuous	I_C	-100	mAdc
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $T_A = 25^\circ\text{C}$	P_D	625 5.0	mW mW/ $^\circ\text{C}$
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $T_A = 25^\circ\text{C}$	P_D	1.5 12	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$

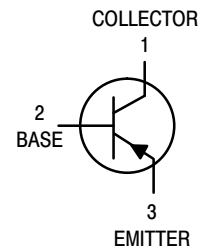
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

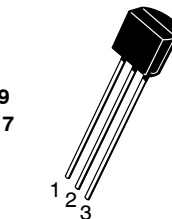


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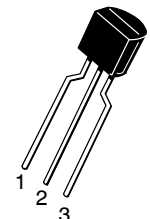
<http://onsemi.com>



TO-92
CASE 29
STYLE 17

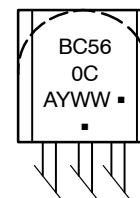


STRAIGHT LEAD
BULK PACK



BENT LEAD
TAPE & REEL
AMMO PACK

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping
BC560CG	TO-92 (Pb-Free)	5000 Units / Bulk
BC560CZL1G	TO-92 (Pb-Free)	2000 / Ammo Pack

BC560C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (I _C = -10 mA _{dc} , I _B = 0)	V _{(BR)CEO}	-45	-	-	V _{dc}
Collector – Base Breakdown Voltage (I _C = -10 μA _{dc} , I _E = 0)	V _{(BR)CBO}	-50	-	-	V _{dc}
Emitter – Base Breakdown Voltage (I _E = -10 μA _{dc} , I _C = 0)	V _{(BR)EBO}	-5.0	-	-	V _{dc}
Collector Cutoff Current (V _{CB} = -30 V _{dc} , I _E = 0) (V _{CB} = -30 V _{dc} , I _E = 0, T _A = +125°C)	I _{CBO}	-	-	-15 -5.0	nA _{dc} μA _{dc}
Emitter Cutoff Current (V _{EB} = -4.0 V _{dc} , I _C = 0)	I _{EBO}	-	-	-15	nA _{dc}
ON CHARACTERISTICS					
DC Current Gain (I _C = -10 μA _{dc} , V _{CE} = -5.0 V _{dc}) (I _C = -2.0 mA _{dc} , V _{CE} = -5.0 V _{dc})	h _{FE}	100 380	270 500	- 800	-
Collector – Emitter Saturation Voltage (I _C = -10 mA _{dc} , I _B = -0.5 mA _{dc}) (I _C = -10 mA _{dc} , I _B = (Note 1)) (I _C = -100 mA _{dc} , I _B = -5.0 mA _{dc} , (Note 2))	V _{CE(sat)}	- - -	-0.075 -0.3 -0.25	-0.25 -0.6 -	V _{dc}
Base – Emitter Saturation Voltage (I _C = -100 mA _{dc} , I _B = -5.0 mA _{dc})	V _{BE(sat)}	-	-1.1	-	V _{dc}
Base – Emitter On Voltage (I _C = -10 μA _{dc} , V _{CE} = -5.0 V _{dc}) (I _C = -100 μA _{dc} , V _{CE} = -5.0 V _{dc}) (I _C = -2.0 mA _{dc} , V _{CE} = -5.0 V _{dc})	V _{BE(on)}	- - -0.55	-0.52 -0.55 -0.62	- - -0.7	V _{dc}
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (I _C = -10 mA _{dc} , V _{CE} = -5.0 V _{dc} , f = 100 MHz)	f _T	-	250	-	MHz
Collector – Base Capacitance (V _{CB} = -10 V _{dc} , I _E = 0, f = 1.0 MHz)	C _{cbo}	-	2.5	-	pF
Small – Signal Current Gain (I _C = -2.0 mA _{dc} , V _{CE} = -5.0 V, f = 1.0 kHz)	h _{fe}	450	600	900	-
Noise Figure (I _C = -200 μA _{dc} , V _{CE} = -5.0 V _{dc} , R _S = 2.0 kΩ, f = 1.0 kHz) (I _C = -200 μA _{dc} , V _{CE} = -5.0 V _{dc} , R _S = 100 kΩ, f = 1.0 kHz, Δf = 200 kHz)	NF ₁ NF ₂	- -	0.5 -	2.0 10	dB

- I_B is value for which I_C = -11 mA at V_{CE} = -1.0 V.
- Pulse test = 300 μs – Duty cycle = 2%.

BC560C

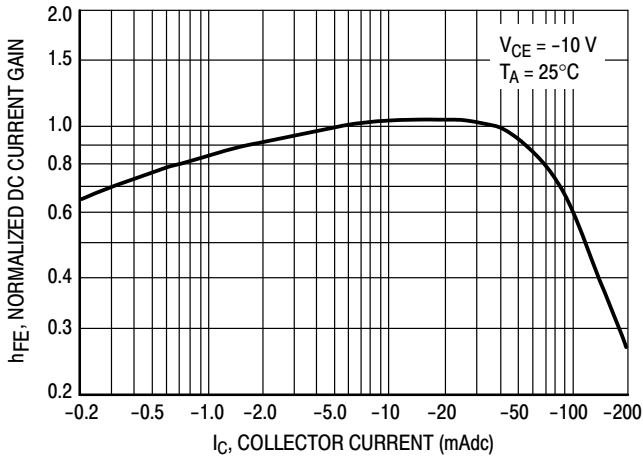


Figure 1. Normalized DC Current Gain

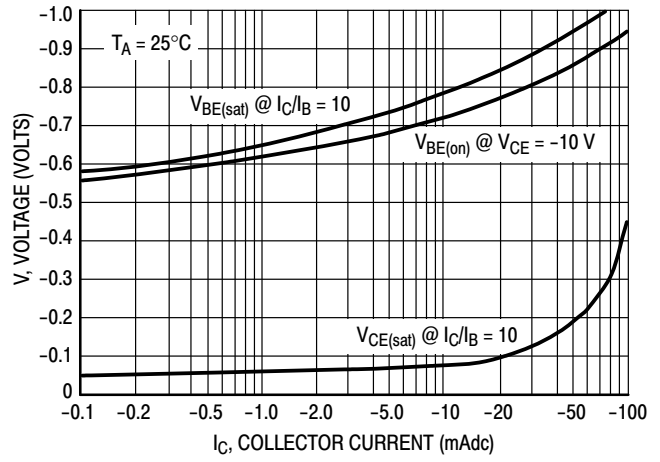


Figure 2. "Saturation" and "On" Voltages

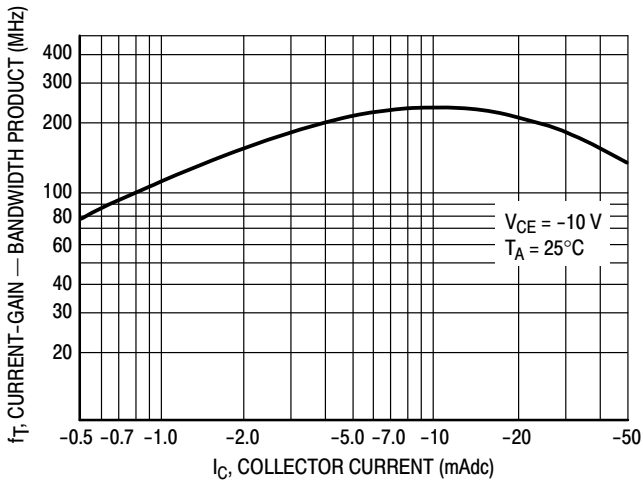


Figure 3. Current-Gain — Bandwidth Product

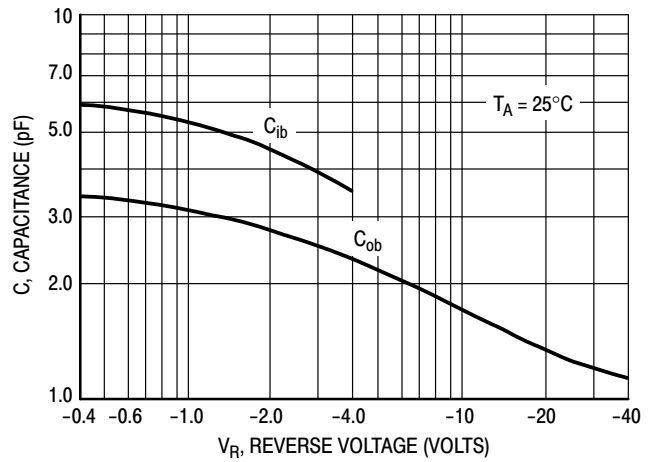


Figure 4. Capacitance

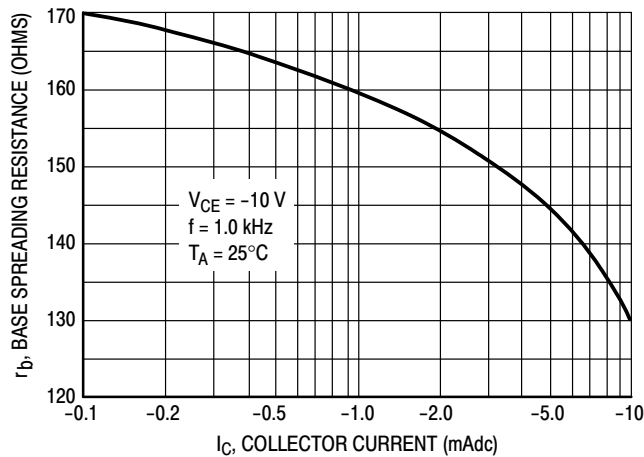
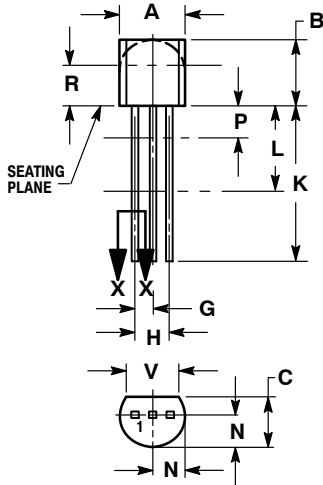


Figure 5. Base Spreading Resistance

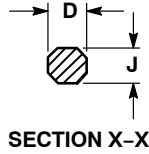
BC560C

PACKAGE DIMENSIONS

TO-92 (TO-226)
CASE 29-11
ISSUE AM



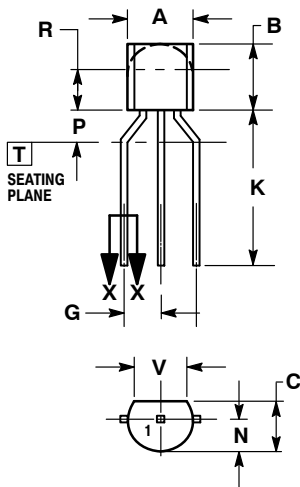
STRAIGHT LEAD
BULK PACK



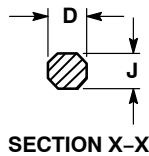
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---



BENT LEAD
TAPE & REEL
AMMO PACK



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
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3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	MILLIMETERS	
	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---

STYLE 17:

1. COLLECTOR
2. BASE
3. EMITTER

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